

Description

The NDS351N uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

V_{DS} = 30V I_D =4A

 $R_{DS(ON)}$ < 38m Ω @ V_{GS}=10V

Application

Battery protection

Load switch Uninterruptible power supply

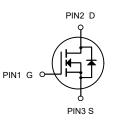
Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
NDS351N	SOT-23	HXY MOSFET	3000

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Symbol	Parameter	Limit	Unit
Vds	Drain-Source Voltage	30	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	4	A
Ырм	Drain Current-Pulsed (Note 1)	16.4	A
PD	Maximum Power Dissipation	1	W
TJ,TSTG	Operating Junction and Storage Temperature Range	-55 To 150	°C
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	125	°C/W





N-Channel MOSFET



Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250µA	30	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V,	-	-	1.0	μA
I _{GSS}	Gate to Body Leakage Current	V_{DS} =0V, V_{GS} = ±20V	-	-	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250µA	1.0	1.5	2.5	V
D	Static Drain-Source on-Resistance	V _{GS} =10V, I _D =4A	-	29	38	mΩ
$R_{DS(on)}$		V _{GS} =4.5V, I _D =3A	-	45	65	
Ciss	Input Capacitance		-	233	-	pF
Coss	Output Capacitance	V _{DS} =15V, V _{GS} =0V, f=1.0MHz	-	44	-	pF
Crss	Reverse Transfer Capacitance		-	33	-	pF
Qg	Total Gate Charge	V _{DS} =15V, I _D =2A,	-	3	-	nC
Q _{gs}	Gate-Source Charge		-	0.5	-	nC
Q_{gd}	Gate-Drain("Miller") Charge	V _{GS} =10V	-	0.8	-	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =15V, I _D =4A, R _{GEN} =3Ω,	-	4	-	ns
tr	Turn-on Rise Time		-	2.1	-	ns
t _{d(off)}	Turn-off Delay Time		-	15	-	ns
t _f	Turn-off Fall Time	V _{GS} =10V	-	3.2	-	ns
ls	Maximum Continuous Drain to Source Diode Forward Current		-	-	4	А
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	16	А
V _{SD}	Drain to Source Diode Forward Voltage	V _{GS} =0V, I _S =4A	-	-	1.2	V

Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%



Typical Characteristics

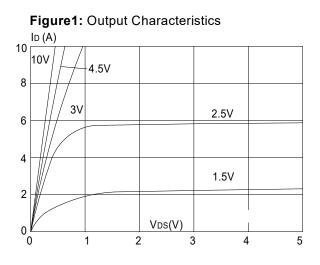
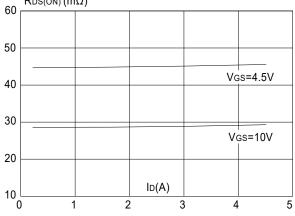
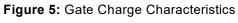
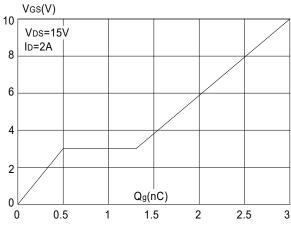


Figure 3:On-resistance vs. Drain Current $RDS(ON)(m\Omega)$







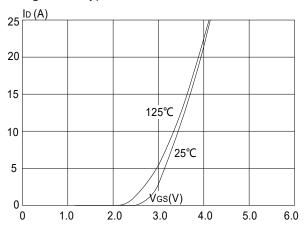
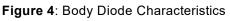
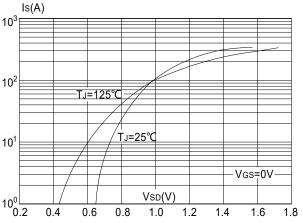


Figure 2: Typical Transfer Characteristics





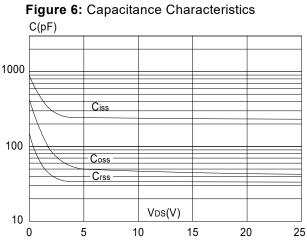




Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

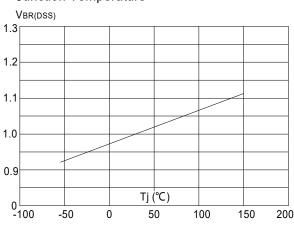


Figure 9: Maximum Safe Operating Area

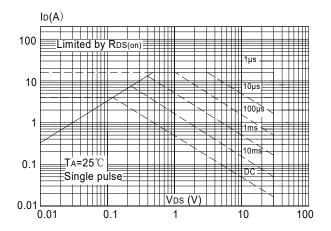
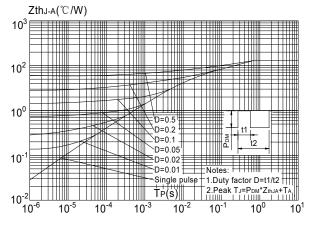


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



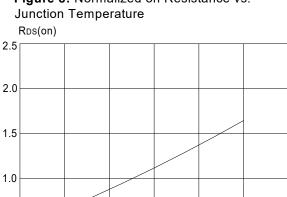


Figure 8: Normalized on Resistance vs.

Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

Tj (℃)

100

150

200

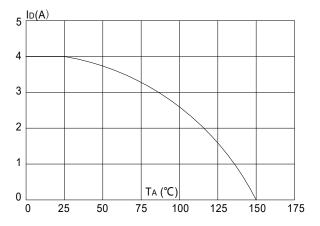
50

0

0.5

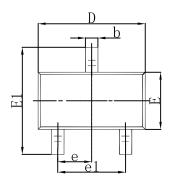
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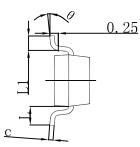
-50

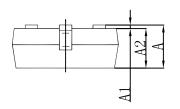




SOT-23 Package Outline Dimensions

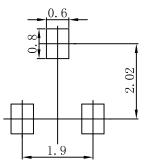






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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